TinyLogic UHS Inverter, Open Drain Output

NC7SZ05

Description

The NC7SZ05 is a single inverter with open drain output stage from **onsemi**'s Ultra–High Speed series of TinyLogic. The device is fabricated with advanced CMOS technology to achieve ultra–high speed with high output drive while maintaining low static power dissipation over a broad V_{CC} operating range. The device is specified to operate over the 1.65 V to 5.5 V V_{CC} operating range. The inputs and output are high–impedance when V_{CC} is 0 V. Inputs tolerate voltages up to 5.5 V, independent of V_{CC} when in the high–impedance state.

Features

- Ultra-High Speed: t_{PD} =1.9 ns (Typical) into 50 pF at 5 V V_{CC}
- Open Drain Output for OR Tied Applications
- High Output Drive: ±24 mA at 3 V V_{CC}
- Broad V_{CC} Operating Range: 1.65 V to 5.5 V
- Matches Performance of LCX Operated at 3.3 V V_{CC}
- Power Down High–Impedance Inputs / Outputs
- Over-Voltage Tolerance Inputs Facilitate 5 V to 3 V Translation
- Proprietary Noise / EMI Reduction Circuitry Implemented
- Ultra-Small MicroPakTM Packages
- Space–Saving SOT23–5, SC–74A and SC–88A Packages
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

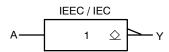
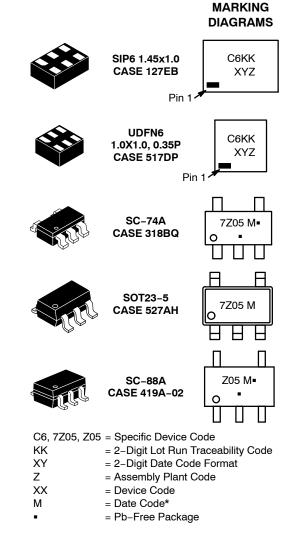


Figure 1. Logic Symbol



(Note: Microdot may be in either location)

*Date Code orientation and/or position may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 5 of this data sheet.

Pin Configurations

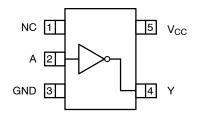


Figure 2. SOT23-5, SC-88A and SC-74A (Top View)

PIN DEFINITIONS

Pin # SOT23-5 / SC-88A / SC74-A	Pin # MicroPak	Name	Description
1	1, 5	NC	No Connect
2	2	А	Input
3	3	GND	Ground
4	4	Y	Output
5	6	V _{CC}	Supply Voltage

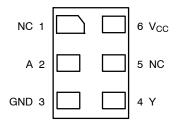


Figure 3. MicroPak (Top Through View)

FUNCTION TABLE

Inputs	Output
А	Y
L	*H
Н	L

H = HIGH Logic Level L = LOW Logic Level *H = High Impedance Output State, Open Drain

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter		Min	Max	Unit
V _{CC}	Supply Voltage		-0.5	6.5	V
V _{IN}	DC Input Voltage		-0.5	6.5	V
V _{OUT}	DC Output Voltage		-0.5	6.5	V
I _{IK}	DC Input Diode Current	V _{IN} < 0 V	-	-50	mA
I _{OK}	DC Output Diode Current	V _{OUT} < 0 V	-	-50	mA
I _{OUT}	DC Output Current		-	±50	mA
I_{CC} or I_{GND}	DC V _{CC} or Ground Current		-	±50	mA
T _{STG}	Storage Temperature Range		-65	+150	°C
ТJ	Junction Temperature Under Bias		-	+150	°C
ΤL	Junction Lead Temperature (Solde	ering, 10 Seconds)	-	+260	°C
PD	Power Dissipation in Still Air	SC-74A / SOT23-5	-	390	mW
		SC-88A	-	332	
		MicroPak-6	-	812	
		MicroPak2™–6	-	812	
ESD	Human Body Model, JEDEC: JES	D22-A114	_	4000	V
	Charge Device Model, JEDEC: JE	ESD22-C101	-	2000	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	Supply Voltage Operating		1.65	5.50	V
	Supply Voltage Data Retention		1.50	5.50	
V _{IN}	Input Voltage		0	5.5	V
V _{OUT}	Output Voltage		0	5.5	V
T _A	Operating Temperature		-40	+85	°C
t _r , t _f	t _f Input Rise and Fall Times	V_{CC} at 1.8 V, 2.5 V ± 0.2 V	0	20	ns/V
		V_{CC} at 3.3 V ± 0.3 V	0	10	
		V_{CC} at 5.0 V ± 0.5 V	0	5	
θ_{JA}	Thermal Resistance	SC-74A / SOT23-5	-	320	°C/W
		SC-88A	-	377	
		MicroPak-6	-	154	
		MicroPak2-6	-	154	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability. 1. Unused inputs must be held HIGH or LOW. They may not float.

NC7SZ05

DC ELECTICAL CHARACTERISTICS

				T _A = +25°C			T _A = −40 to +85°C		
Symbol	Parameter	V _{CC} (V)	Conditions	Min	Тур	Max	Min	Max	Unit
VIH	HIGH Level Input Voltage	1.65 to 1.95		0.65 V _{CC}	-	-	0.65 V _{CC}	-	V
		2.30 to 5.50		0.70 V _{CC}	-	-	0.70 V _{CC}	-	
V _{IL}	LOW Level Input Voltage	1.65 to 1.95		-	-	$0.35 V_{CC}$	-	0.35 V _{CC}	V
		2.30 to 5.50		-	-	0.30 V _{CC}	-	0.30 V _{CC}	
I _{LKG}	HIGH Level Output Leakage Current	1.65 to 5.50		-	_	±5	-	±10	μΑ
V _{OL}	$\begin{array}{c} V_{OL} \\ V_{OL} \\ \hline \\ & U_{IN} = V_{IH} \text{ or } V_{IL}, \\ \hline \\ & 1.80 \\ \hline \\ & 2.30 \end{array}$	-	0.00	0.10	-	0.10	V		
		1.80	- I _{OL} = 100 μΑ	-	0.00	0.10	-	0.10	
		2.30		-	0.00	0.10	-	0.10	
		3.00		-	0.00	0.10	-	0.10	
		4.50		-	0.00	0.10	-	0.10	
		1.65	I _{OL} = 4 mA	-	0.80	0.24	-	0.24	
		2.30	I _{OL} = 8 mA	-	0.10	0.30	-	0.30	
		3.00	l _{OL} = 16 mA	-	0.15	0.40	-	0.40	
		3.00	I _{OL} = 24 mA	-	0.22	0.55	-	0.55	
		4.50	I _{OL} = 32 mA	-	0.22	0.55	-	0.55	
I _{IN}	Input Leakage Current	1.65 to 5.5	$0 \leq V_{IN} \leq 5.5 \ V$	-	-	±1	-	±10	μA
I _{OFF}	Power Off Leakage Current	0	V_{IN} or V_{OUT} = 5.5 V	-	-	1	-	10	μA
I _{CC}	Quiescent Supply Current	1.65 to 5.50	V _{IN} = 5.5 V, GND	-	-	2	-	20	μA

AC ELECTRICAL CHARACTERISTICS

				1	Γ _A = +25°C	;	T _A = -40	to +85°C		
Symbol	Parameter	V _{CC} (V)	Conditions	Min	Тур	Max	Min	Max	Unit	
t _{PZL}	Propagation Delay	1.65	$C_{L} = 50 \text{ pF},$	-	5.5	12.9	-	13.4	ns	
	(Figure 4, 5)	1.80	RU = 500 Ω, RD = 500 Ω,	-	4.6	10.5	-	11.0		
		2.50 ±0.20	$V_{IN} = 2 \cdot V_{CC}$	-	3.0	7.0	-	7.5		
		3.30 ±0.30		-	2.4	5.0	-	5.2		
		5.00 ±0.50		-	1.9	4.3	-	4.5		
t _{PLZ}		1.65	$C_{L} = 50 \text{ pF},$	-	5.0	12.9	-	13.4	ns	
		1.80	$\begin{aligned} & R \overline{U} = 500 \ \Omega, \\ & R D = 500 \ \Omega, \\ & V_{\rm IN} = 2 \cdot V_{\rm CC} \end{aligned}$	-	4.1	10.5 -	-	11.0		
		2.50 ±0.20		$V_{IN} = 2 \cdot V_{CC}$	-	2.5	7.0	-	7.5	
		3.30 ±0.30		-	2.1	5.0	-	5.2		
		5.00 ±0.50		-	1.2	4.3	-	4.5		
C _{IN}	Input Capacitance	0.00		-	4.0	-	-	-	pF	
C _{OUT}	Output Capacitance	0.00		-	6.0	-	-	-	pF	
C _{PD}	Power Dissipation Capacitance	3.30		-	3.6	-	-	-	pF	
	(Note 2) (Figure 6)	5.00	1	-	6.5	-	-	-	1	

2. C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle. C_{PD} is related to I_{CCD} dynamic operating current by the expression: $I_{CCD} = (C_{PD}) (V_{CC}) (f_{IN}) + (I_{CC} static).$

NC7SZ05

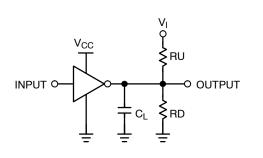
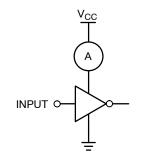


Figure 4. AC Test Circuit





3. Input = AC Waveform; $t_r = t_f = 1.8$ ns; PRR = 10 MHz; Duty Cycle = 50%.

Figure 6. Test Circuit

Device	Top Mark	Packages	Shipping [†]
NC7SZ05M5X	7Z05	5-Lead SC-74A, 1.6mm	3000 / Tape & Reel
NC7SZ05M5X-L22090	7Z05	SOT23-5	3000 / Tape & Reel
NC7SZ05P5X	Z05	5-Lead SC70, EIAJ SC-88A, 1.25 mm Wide	3000 / Tape & Reel
NC7SZ05P5X-L22057	Z05	5-Lead SC70, EIAJ SC-88A, 1.25 mm Wide	3000 / Tape & Reel
NC7SZ05L6X	C6	6-Lead MicroPak, 1.00 mm Wide	5000 / Tape & Reel
NC7SZ05L6X-L22175	C6	6-Lead MicroPak, 1.00 mm Wide	5000 / Tape & Reel
NC7SZ05FHX	C6	6-Lead, MicroPak2, 1 x 1 mm Body, 0.35 mm Pitch	5000 / Tape & Reel
NC7SZ05FHX-L22175	C6	6–Lead, MicroPak2, 1 x 1 mm Body, 0.35 mm Pitch	5000 / Tape & Reel

DEVICE ORDERING INFORMATION

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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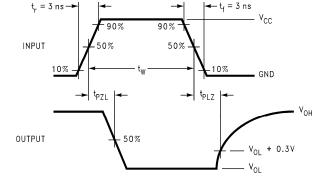


Figure 5. AC Waveforms

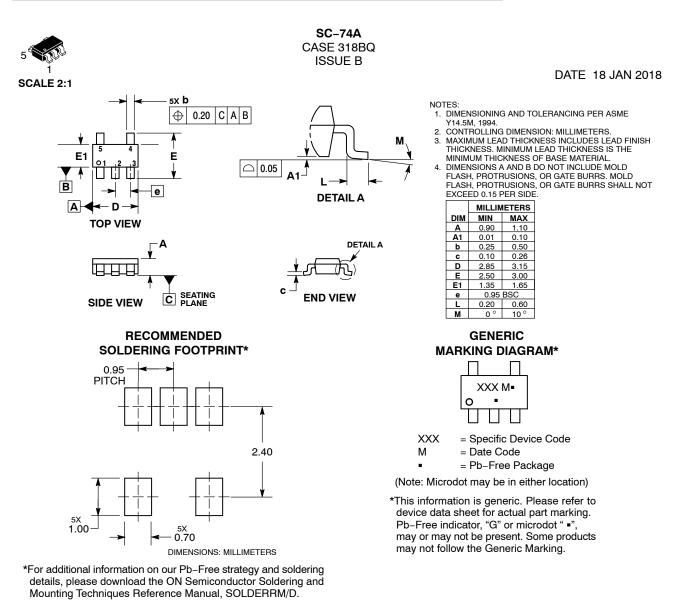


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DATE 31 AUG 2016







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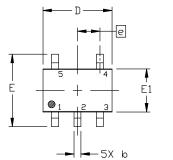
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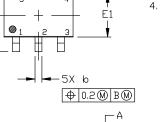
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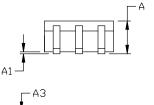
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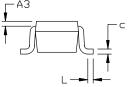
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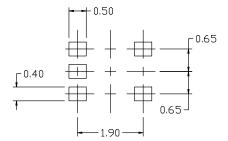
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RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

DIM	MILLIMETERS			
MIU	MIN.	NDM.	MAX.	
A	0.80	0.95	1.10	
A1			0.10	
A3	0.20 REF			
b	0.10	0.20	0.30	
С	0.10		0.25	
D	1.80	2.00	5'50	
E	2.00	2.10	5'50	
E1	1.15	1.25	1.35	
e	0.65 BSC			
L	0.10	0.15	0.30	

DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH,

PROTRUSIONS, OR GATE BURRS.MOLD FLASH, PROTRUSIONS,

OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

CONTROLLING DIMENSION: MILLIMETERS 419A-01 DBSOLETE, NEW STANDARD 419A-02

GENERIC MARKING





*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

XXX = Specific Device Code

Μ = Date Code = Pb-Free Package

(Note: Microdot may be in either location)

STYLE 1: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 5. COLLECTOR	STYLE 2: PIN 1. ANODE 2. EMITTER 3. BASE 4. COLLECTOR 5. CATHODE	STYLE 3: PIN 1. ANODE 1 2. N/C 3. ANODE 2 4. CATHODE 2 5. CATHODE 1	STYLE 4: PIN 1. SOURCE 1 2. DRAIN 1/2 3. SOURCE 1 4. GATE 1 5. GATE 2	STYLE 5: PIN 1. CATHODE 2. COMMON ANOD 3. CATHODE 2 4. CATHODE 3 5. CATHODE 4	E
STYLE 6: PIN 1. EMITTER 2 2. BASE 2 3. EMITTER 1 4. COLLECTOR 5. COLLECTOR 2/BASE	STYLE 7: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 1 5. COLLECTOR	STYLE 8: PIN 1. CATHODE 2. COLLECTOR 3. N/C 4. BASE 5. EMITTER	STYLE 9: PIN 1. ANODE 2. CATHODE 3. ANODE 4. ANODE 5. ANODE	Note: Please refer to style callout. If style to out in the datasheet r datasheet pinout or p	ype is not called efer to the device
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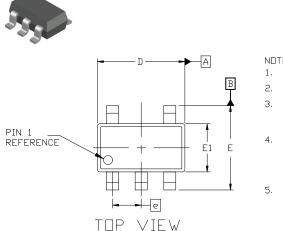
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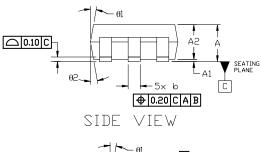


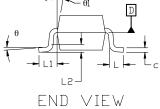
SOT-23, 5 Lead CASE 527AH **ISSUE A**

DATE 09 JUN 2021

NDTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 19894
- CONTROLLING DIMENSION: MILLIMETERS
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL
- DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.25 PER SIDE. D AND E1 DIMENSIONS ARE DETERMINED AT DATUM D.
- DIMENSION 'b' DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08mm TOTAL IN EXCESS OF THE 'b' DIMENSION AT MAXIMUM MATERIAL CONDITION. MINIMUM SPACE BETWEEN PROTRUSION AND AN ADJACENT LEAD SHALL NOT BE LESS THAN 0.07mm.





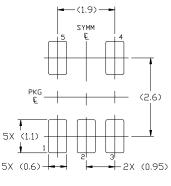
GENERIC **MARKING DIAGRAM***



XXX = Specific Device Code = Date Code М

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

	MILLIMETERS				
DIM	MIN.	NDM.	MAX.		
Α	0.90	—	1.45		
A1	0.00	_	0.15		
A2	0.90	1.15	1.30		
b	0.30	—	0.50		
С	0.08		0.22		
D	2.90 BSC				
E	2.80 BSC				
E1	1.60 BSC				
е	0	0.95 BSC			
L	0.30	0.45	0.60		
L1	0.60 REF				
L2	0.25 REF				
θ	0*	4°	8*		
01	0*	10°	15°		
θ 2	0°	10°	15°		



RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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